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# ULTRAVIOLET LIGHT SENSOR, UV-A to UV-B SENSING SI PHOTODIODE

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The S-5420 is a photodiode (PD) made of silicon that can detect ultraviolet light at high sensitivity. The output current changes in reaction to light which includes ultraviolet light. Therefore, the S-5420 can detect light intensity of various light sources for LEDs and other devices. Since the S-5420 can detect ultraviolet light intensity, it is particularly well suited for use in various light measurement devices which irradiate ultraviolet light.

The S-5420 is composed of two types of ultraviolet photodiodes, a high-sensitivity and a low-sensitivity photodiodes. Using an external circuit, the S-5420 takes the difference of output between the high-sensitivity and low-sensitivity photodiodes, which cuts out visible light components. It results in ultraviolet components detection.

Incorporating a surface-mounting type, small, transparent package, the S-5420 allows for high-density mounting.

**Remark** This product is jointly developed with Sugawa and Kuroda Laboratory of Graduate School of Engineering, Tohoku University.

#### ■ Features

• Wide-range sensitivity wavelength:  $\lambda$  = 250 nm to 1000 nm • High-sensitivity ultraviolet light detection:  $S_H = 0.17 \text{ A/W} (\lambda = 365 \text{ nm})$ 

Ultraviolet components detection:
 As a result of the difference of output between two types of photodiodes

(Requirement: external parts)

· Lead-free, halogen-free

### ■ Applications

- · Light intensity detection of ultraviolet light source
- UV index detection
- · Analytical equipment

#### ■ Package

• SON-6C

### **■** Block Diagram

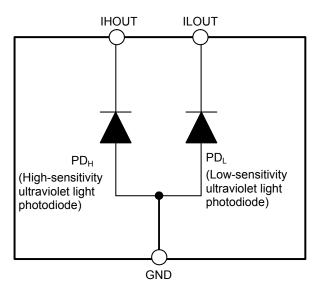
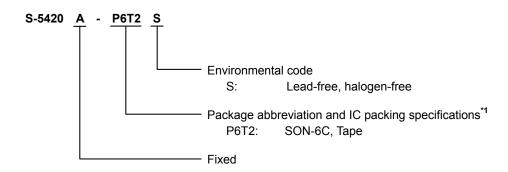


Figure 1

#### 1. Product name

**■** Product Name Structure



\*1. Refer to the tape drawing.

#### 2. Package

Table 1 Package Drawing Codes

Package Name	Dimension	Tape	Reel
SON-6C	PZ006-A-P-SD	PZ006-A-C-SD	PZ006-A-R-SD

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### **■** Pin Configuration

### 1. SON-6C

Top view

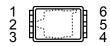


Figure 2

Table 2	
	Des

Pin No.	Symbol	Description
1	GND	GND pin
2	NC <sup>*1</sup>	No connection
3	NC <sup>*1</sup>	No connection
4	ILOUT	Output pin (low-sensitivity ultraviolet light PD)
5	NC <sup>*1</sup>	No connection
6	IHOUT	Output pin (high-sensitivity ultraviolet light PD)

**<sup>\*1.</sup>** The NC pin is electrically open. The NC pin can be connected to the GND pin.

#### ■ Absolute Maximum Ratings

Table 3

 $(Ta = +25^{\circ}C \text{ unless otherwise specified})$ 

Item	Symbol	Absolute Maximum Rating	Unit
Reverse voltage	$V_{R\_max}$	4.0	V
Operation ambient temperature*1	T <sub>opr</sub>	−20 to +70	°C
Storage temperature*1	T <sub>stg</sub>	-40 to +85	°C

<sup>\*1.</sup> Conditions with no condensation or frost.

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.

#### **■** Electrical Characteristics

Table 4

(When mounted on board, Ta = +25°C unless otherwise specified) Item Symbol Condition Min. Max. Unit Тур. Light receiving area (one photodiode) Α 0.20  $mm^2$  $V_{\text{IHOUT}}$ , Output pin voltage\*1 ٧ 0 0.5  $V_{\text{ILO}\underline{\text{UT}}}$ 250 to 1000  $(\lambda_p^{*2} = 420)$ λ Sensitivity wavelength range  $V_{IHOUT} = 0.3 \text{ V}, V_{ILOUT} = 0.3 \text{ V}$ nm Sensitivity  $V_{IHOUT} = 0.3 \text{ V}, V_{ILOUT} = 0.3 \text{ V}$  $\lambda = 365 \text{ nm} \mid 0.136$  $S_H$ 0.170 A/W (high-sensitivity ultraviolet light PD)  $S_L$  $V_{IHOUT} = 0.3 \text{ V}, V_{ILOUT} = 0.3 \text{ V}$  $\lambda = 365 \text{ nm}$ 0.020 A/W (low-sensitivity ultraviolet light PD)  $\lambda$  = 365 nm 0.120 0.150 A/W Differential sensitivity (S<sub>H</sub> - S<sub>L</sub>)  $S_D$  $V_{IHOUT} = 0.3 \text{ V}, V_{ILOUT} = 0.3 \text{ V}$  $\lambda$  = 520 nm 0.020 0.040 A/W Dark current  $V_{IHOUT} = 0.3 \text{ V}, V_{ILOUT} = 0.3 \text{ V}$ 5 300 pΑ

#### **■ Test Circuit**

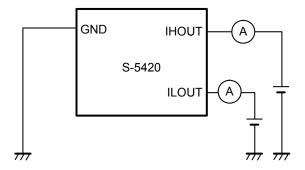


Figure 3

<sup>\*1.</sup> Voltage applied to the output pin

<sup>\*2.</sup>  $\lambda_p$ : Peak sensitivity wavelength

#### ■ Standard Circuits

#### 1. Standard circuit

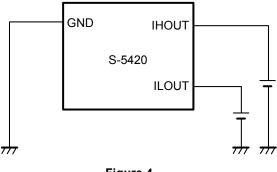


Figure 4

#### 2. Standard circuit when using only high-sensitivity ultraviolet light PD

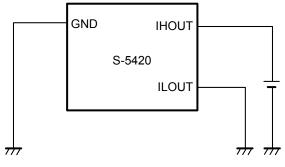


Figure 5

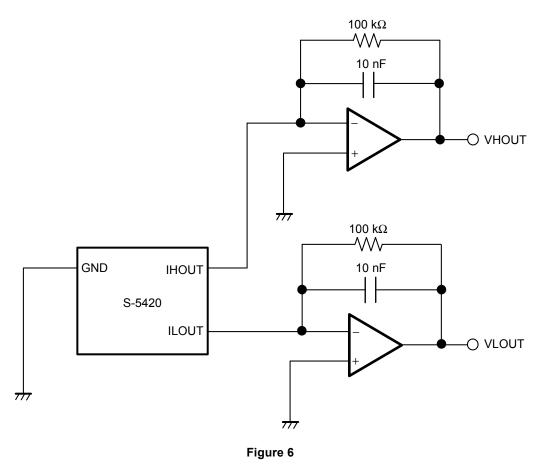
Caution The above connection diagrams will not guarantee successful operation.

Perform thorough evaluation using the actual application to set the constants.

### ■ Application Circuit

#### 1. I/V conversion circuit

Voltage proportional to the irradiation light is output.



Caution The above connection diagram and constants will not guarantee successful operation. Perform thorough evaluation using the actual application to set the constants.

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#### ■ Precautions for Package

The SON-6C package is compatible with a reflow soldering. Do not implement a hand soldering.

• The reflow profile in mounting evaluation of the SON-6C package is shown as below.

Preheating: 180°C, 90 s

Heating: 217°C to 260°C, 60 s to 80 s

Peak heating: 260°C, within 10 s

Temperature measurement point: Topside of the package (resin surface)

Number of maximum reflow cycle: 1 time

- The optical characteristics may vary according to the reflow profile.
- The moisture sensitivity level of the SON-6C package is MSL 3. Do not use and store this package at high humidity.
   Packages tend to absorb moisture from the ambient atmosphere. If sudden heating is conducted in the process of a reflow soldering under moisture-absorbed condition, the moisture would vaporize and expand. It may cause interfacial delamination between the S-5420 chip and resin, package cracks, and other damages.
- The storage requirements after a moisture barrier bag is opened are as follows;

Condition: ≤30°C/60% RH Storage period: 168 hours

If the above storage period exceeded, implement a reflow soldering after baking for 24 hours to 48 hours at Ta = 65°C.

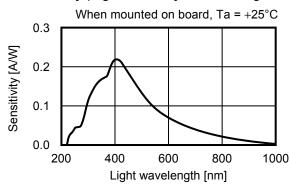
#### ■ Precautions

8

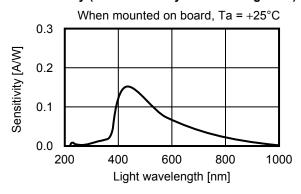
- Irradiating ultraviolet light for a long time may result in characteristic degradation such as sensitivity deterioration. Perform sufficient light-exposure evaluation before using the S-5420 under ultraviolet light irradiation environment.
- Do not apply an excessive electrostatic discharge to the S-5420.
- Large stress on the S-5420 may affect the sensitivity characteristics. Avoid large stress which is caused by the handling during or after mounting the IC on a board.
- ABLIC Inc. claims no responsibility for any disputes arising out of or in connection with any infringement by products including the S-5420 of patents owned by a third party.

### ■ Characteristics (Typical Data)

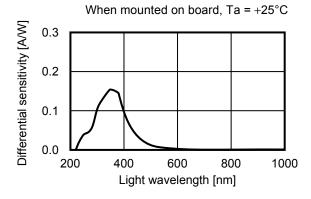
### 1. Sensitivity (High-sensitivity ultraviolet light PD)



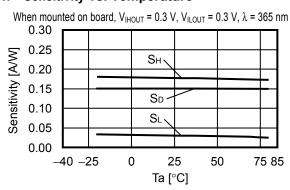
#### 2. Sensitivity (Low-sensitivity ultraviolet light PD)



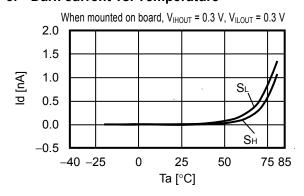
#### 3. Differential sensitivity (High-sensitivity ultraviolet light PD – Low-sensitivity ultraviolet light PD)



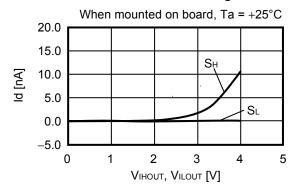
#### 4. Sensitivity vs. Temperature



#### 5. Dark current vs. Temperature



#### 6. Dark current vs. Reverse voltage



#### 7. Light exposure

Test method: After irradiating the test light to a mount board, measuring the sensitivity.

Irradiation light at measurement: 300 nm, 365 nm Measurement timing: 0 hours, 500 hours, 1000 hours

#### 7. 1 Light exposure 1

Light source for test: Super Xenon Weather Meter (SX75)

(JIS B7754:1991 / Specified in light-exposure and light-and-water-exposure test apparatus (Xenon-arc lamp type))

Test conditions

Irradiance: 180 W/m<sup>2</sup> (300 nm to 400 nm) Irradiation time: 1000 hours

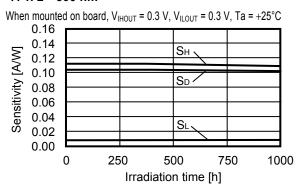
Inner filter: quartz Outer filter: #275

Black panel temperature:  $63 \pm 3^{\circ}$ C Relative humidity:  $50 \pm 10\%$ 

#### 7. 1. 1 365 nm

#### When mounted on board, $V_{IHOUT} = 0.3 \text{ V}$ , $V_{ILOUT} = 0.3 \text{ V}$ , $Ta = +25^{\circ}C$ 0.30 0.25 Sensitivity [A/W] Sн 0.20 0.15 SD 0.10 SL 0.05 0.00 0 250 500 750 1000 Irradiation time [h]

#### 7. 1. 2 300 nm



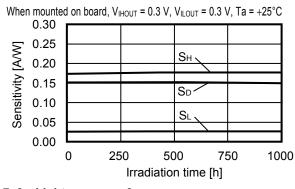
#### 7. 2 Light exposure 2

Light source for test: 365 nm LED (NSSU100CT)

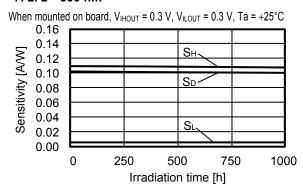
Test conditions

Irradiance: 250 μW/cm<sup>2</sup> Irradiation time: 1000 hours

#### 7. 2. 1 365 nm



#### 7. 2. 2 300 nm



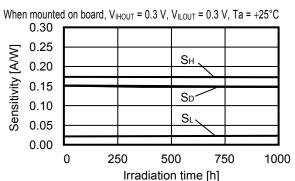
### 7. 3 Light exposure 3

Light source for test: 300 nm LED (VPS1A1)

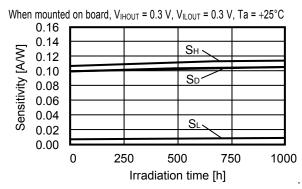
Test conditions

Irradiance: 250 μW/cm<sup>2</sup> Irradiation time: 1000 hours

#### 7. 3. 1 365 nm

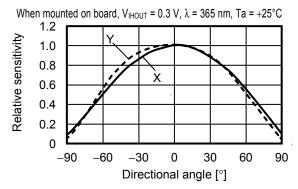


#### 7. 3. 2 300 nm

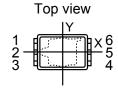


#### 8. Directivity characteristics

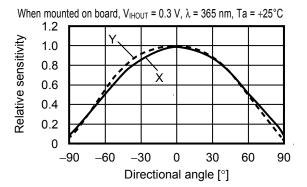
#### 8.1 PD<sub>H</sub>



Remark X, Y: Rotation axes



#### 8. 2 PD<sub>L</sub>



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### ■ Marking Specifications

#### 1. SON-6C

Bottom view

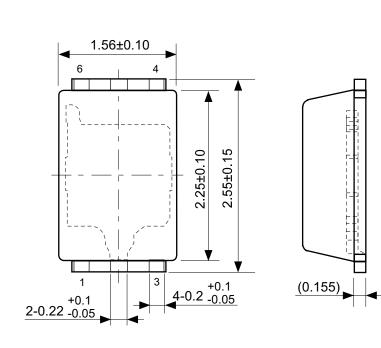
6 (1) (2) (3) 1
5 (4) (5) (6) 3

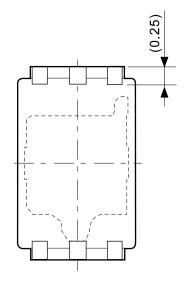
(1) to (3): Product code (refer to **Product name vs. Product code**)

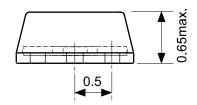
(4) to (6): Lot number

#### Product name vs. Product code

Doe do et Neves	Product Code			
Product Name	(1)	(2)	(3)	
S-5420A-P6T2S	Z	Υ	J	

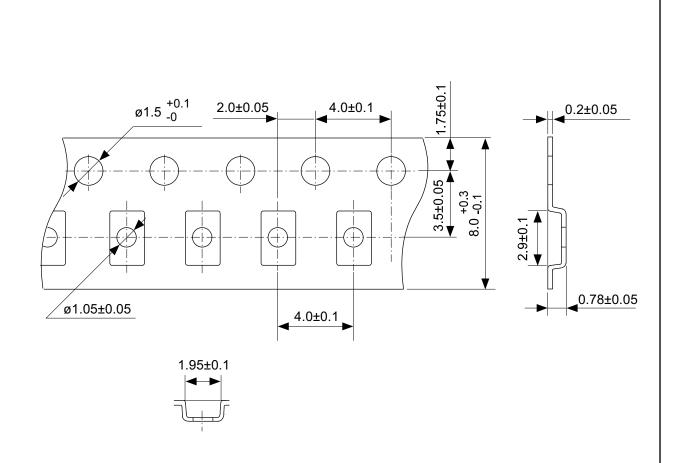


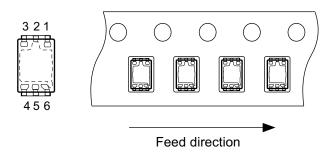




### No. PZ006-A-P-SD-1.0

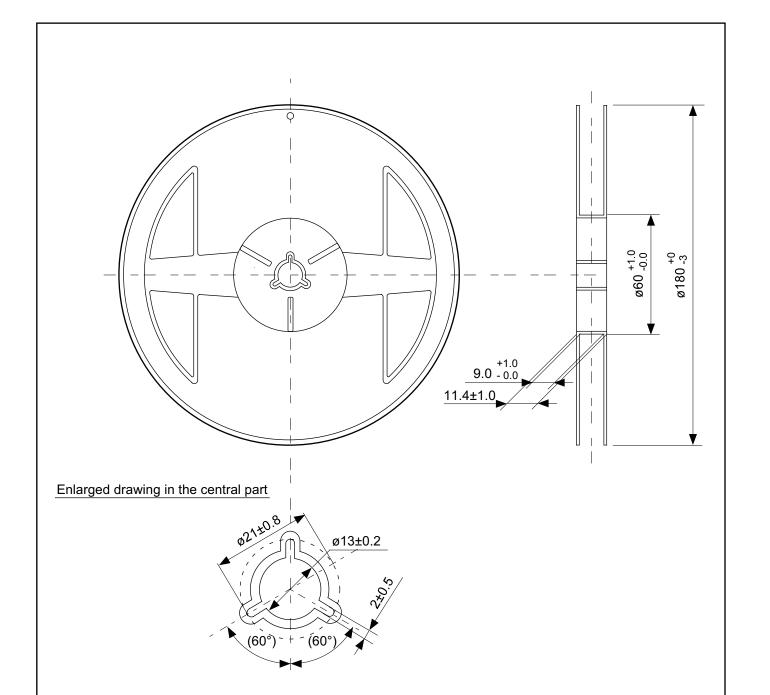
TITLE	SON-6C-A-PKG Dimensions	
No.	PZ006-A-P-SD-1.0	
ANGLE	<b>\$</b>	
UNIT	mm	
ABLIC Inc.		





## No. PZ006-A-C-SD-1.0

TITLE	SON-6C-A-Carrier Tape		
No.	PZ006-A-C-SD-1.0		
ANGLE			
UNIT	mm		
ABLIC Inc.			



## No. PZ006-A-R-SD-1.0

TITLE	SON-6C-A-Reel		
No.	PZ006-A-R-SD-1.0		
ANGLE		QTY	3000
UNIT	mm		
ABLIC Inc.			

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